INA5001AC1

This is not a final specification.

Some parameters are subject to change.

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE (mini type)

DESCRIPTION

INA5001AC1 is a super mini package resin sealed silicon PNP epitaxial transistor,

It is designed for relay draive or Power supply application.

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FEATURE

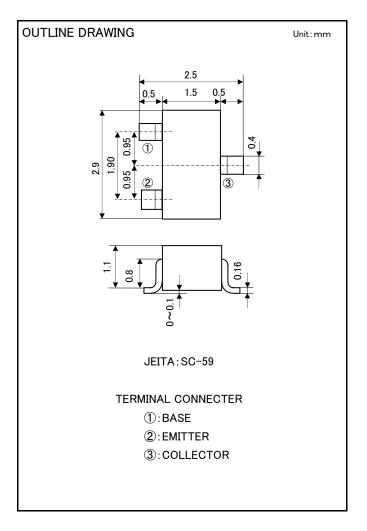
- Super mini package for easy mounting
- Low VCE(sat) V_{CE(sat)}=-0.5 V max(@Ic=-500mA/IB=-50mA)
- High collector current Ic=-1A
- High voltage VcEo=-50V

APPLICATION

Relay drive, Power supply for audio equipment, VTR, etc

MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Parameter Ratings	
V _{CBO}	Collector to Base voltage	-50	٧
V_{EBO}	Emitter to Base voltage	-5	٧
V _{CEO}	Collector to Emitter voltage	-50	٧
I c	Collector current	-1	Α
Ісм	Peak collector current -2		Α
Pc	Collector dissipation 200		mW
Tj	Junction temperature	+150	°C
T_{stg}	Storage temperature	-55 ~ + 150	°C



ELECTRICAL CHARACTERISTICS (Ta=25°C)

Parameter	Symbol	Test conditions	Limits			Unit
Farameter			Min	Тур	Max	Unit
C to B break down voltage	V(BR)cво	$I_{C}=-10 \mu A$, $I_{E}=0$	-50	-	-	٧
E to B break down voltage	V(BR) _{EBO}	I_{E} =-10 μ A , I_{C} =0	-5	-	-	٧
C to E break down voltage	V(BR)ceo	I _C =−1mA ,R _{BE} =∞	-50	-	-	٧
Collector cut off current	Ісво	V_{CB} =-50V, I_{E} =0mA	-	-	-0.1	uA
Emitter cut off current	I EBO	V_{EB} =-5V, I $_{C}$ =0mA	-	-	-0.1	uA
DC forward current gain	hFE	V _{CE} =-4V, I _C =-0.1A	160	1	380	
C to E Saturation Voltage	V _{CE(sat)}	I_{C} =-500mA , I_{B} =-50mA	ı	-	-0.5	٧
Gain bandwidth product	fT	V _{CE} =-2V, I _E =500mA	-	120	-	MHz
Collector output capacitance	Cob	V _{CB} =-10V, I _E =0mA,f=1MHz	_	12	-	pF

TENTATIVE

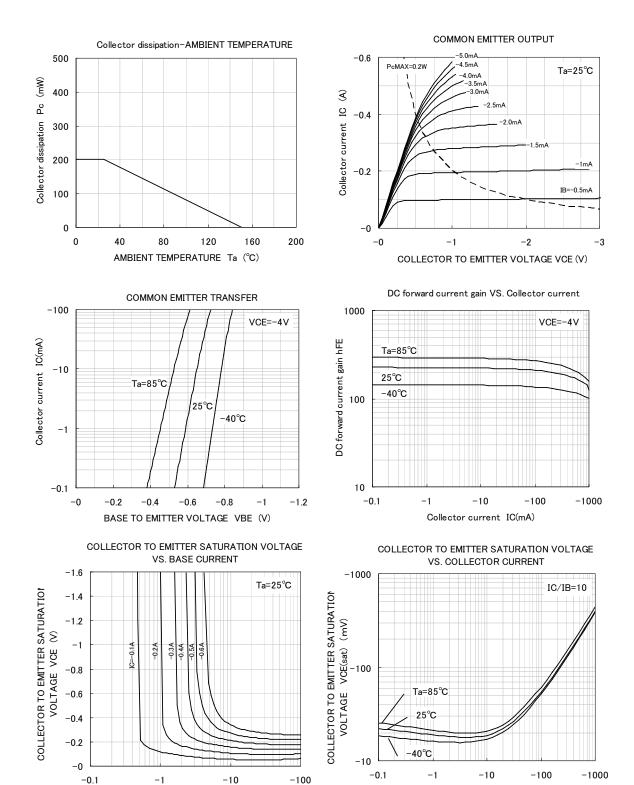
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COLLECTOR CURRENT IC(mA)



BASE CURRENT IB (mA)

TENTATIVE

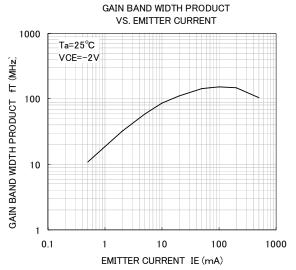
(SMALL-SIGNAL TRANSISTOR)

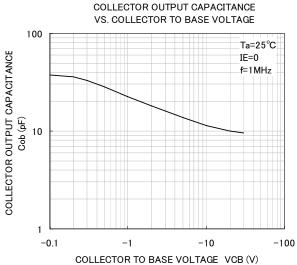
INA5001AC1

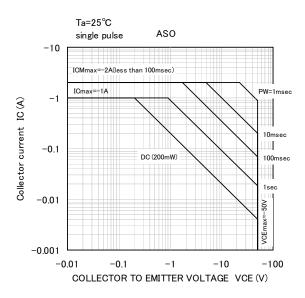
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FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE (mini type)









Marketing division, Marketing planning department

6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

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